SQJ414EP

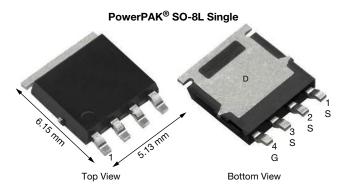
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Automotive N-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY	
V _{DS} (V)	30
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0120
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0170
I _D (A)	30
Configuration	Single

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

N-Channel MOSFET



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ414EP (for detailed order number please see <u>www.vishay.com/doc?79771</u>)

ABSOLUTE MAXIMUM RATINGS (T	$_{\rm C}$ = 25 °C, unless	s otherwise noted	I)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	30	V	
Gate-source voltage		V _{GS}	± 20		
Continuous drain current	$T_C = 25 \ ^{\circ}C \ ^{a}$	L_	30		
Continuous drain current	T _C = 125 °C	ID	25		
Continuous source current (diode conduction) a		I _S	30	A	
Pulsed drain current ^b		I _{DM}	90		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	22		
Single pulse avalanche energy		E _{AS}	24.2	mJ	
Maximum power dissipation ^b	T _C = 25 °C	45 W			
maximum power dissipation 5	T _C = 125 °C	P _D	15	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) d, e			260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction to ambient P	PCB mount ^c	R _{thJA}	70	°C/W
Junction to case (drain)		R _{thJC}	3.3	0/10

Notes

a. Package limited

- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$, t	unless otherv	vise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static	•	•					
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	- V _{GS} , I _D = 250 μΑ	1.5	2.0	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 30 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	15	-	-	А
		$V_{GS} = 10 V$	I _D = 4.5 A	-	0.0098	0.0120	
Drain aguras en stata registance à	Р	$V_{GS} = 4.5 V$	I _D = 3 A	-	0.0139	0.0170	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 4.5 A, T _J = 125 °C	-	-	0.0188	V nA μA A 0 3 PF nC Ω nR N
		$V_{GS} = 10 V$	I _D = 4.5 A, T _J = 175 °C	-	-	0.0227	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 4 A	-	31	-	S
Dynamic ^b					•		•
Input capacitance	C _{iss}			-	850	1110	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 15 V, f = 1 MHz	-	167	220	pF
Reverse transfer capacitance	C _{rss}			-	60	80	
Total gate charge ^c	Qg			-	15	25	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	V _{DS} = 15 V, I _D = 5 A	-	3	-	nC
Gate-drain charge ^c	Q _{gd}			-	3	-	
Gate resistance	Rg		f = 1 MHz	0.7	1.5	2.3	Ω
Turn-on delay time ^c	t _{d(on)}			-	11	20	
Rise time ^c	t _r	V _{DD} =	= 15 V, R _I = 3.8 Ω	-	5	10	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 4 \text{ A}, $	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	21	40	ns
Fall time ^c	t _f			-	5	10	
Source-Drain Diode Ratings and Chara	cteristics ^b	•					
Pulsed current ^a	I _{SM}			-	-	90	Α
Forward voltage	V _{SD}	١ _F	= 4 A, V _{GS} = 0	-	0.79	1.2	V
Body diode reverse recovery time	t _{rr}			-	22	50	ns
Body diode reverse recovery charge	Q _{rr}	1		-	18	40	nC
Reverse recovery fall time	ta	I _F = 3	A, di/dt = 100 A/µs	-	14	-	
Reverse recovery rise time	t _b	1		-	8	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.5	-	А

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. Guaranteed by design, not subject to production testing

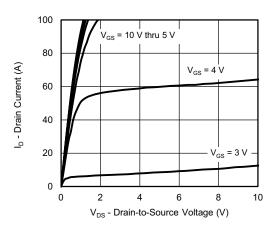
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

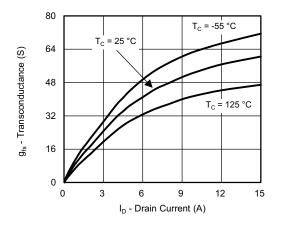
2



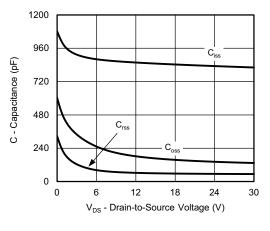
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



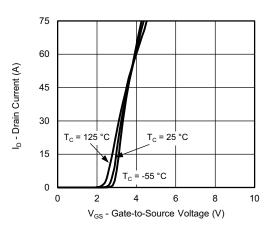
Output Characteristics



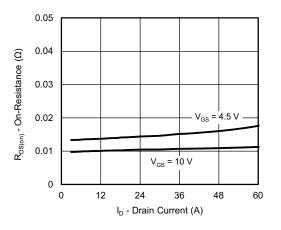
Transconductance



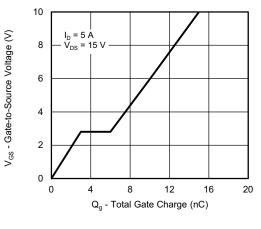
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current



Gate Charge

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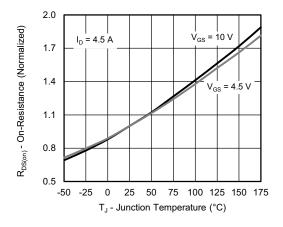
3

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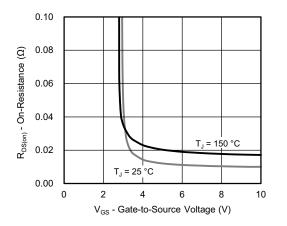
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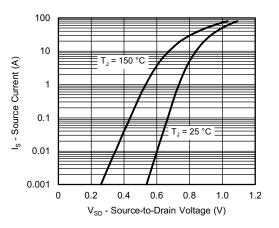
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



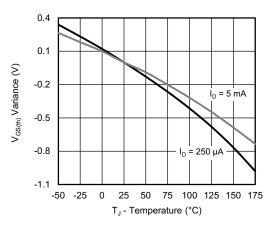
On-Resistance vs. Junction Temperature

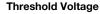


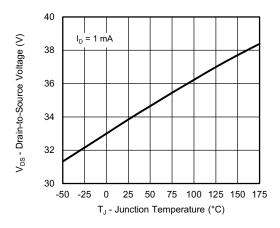
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







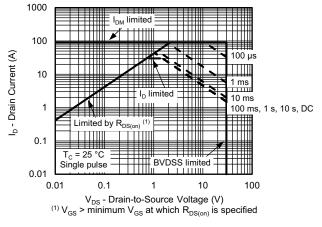
Drain Source Breakdown vs. Junction Temperature

4

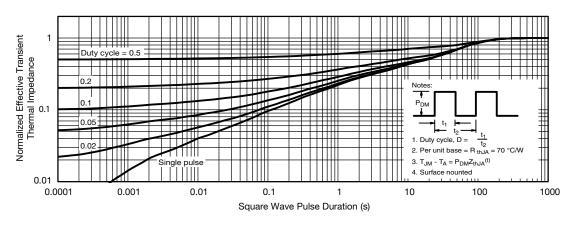
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

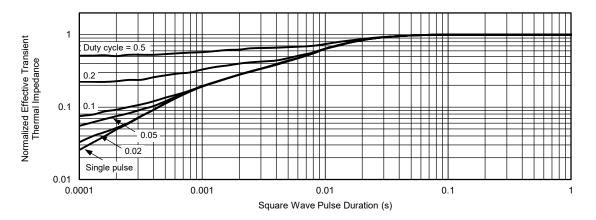


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

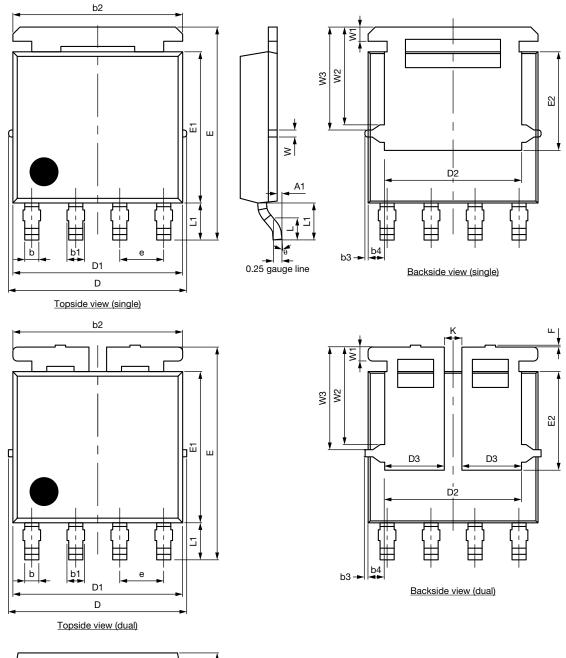
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

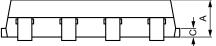
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Package Information



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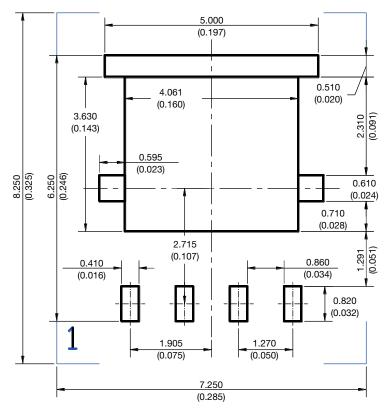
DIM.		MILLIMETERS			INCHES			
	MIN.	NOM. MAX. MIN.			MIN. NOM.			
А	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094			0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC		0.050 BSC				
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
К		0.51			0.020			
W		0.23			0.009			
W1		0.41			0.016			
W2	2.82			0.111				
W3		2.96			0.117			
θ	0°	-	10°	0°	-	10°		

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK[®] SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)

Revision: 07-Feb-12



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